

SANYO Semiconductors DATA SHEET



Monolithic Linear IC LA6567H — For MD and CD Player **Five-Channel Motor Driver** (four BTL channels plus one H bridge channel)

Overview

The LA6567H is a motor driver IC for MD and CD players with four BTL channels and one H bridge channel. The LA6567H features a separate power supply for the H bridge block, an output adjustment pin, and a 5V regulator to support a wide range of applications.

Functions

- Power amplifier 4-channel (BTL) and 1-channel (H bridge) built-in.
- IO max 700mA (Each channel)
- Level shift circuit built-in (BTL AMP).
- Overheat protection circuit (thermal shutdown) built-in.
- With loading output voltage setting function
- 5V regulator built-in.

Specifications

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions Ratings		Unit
Supply voltage	V _{CC} max		14	V
Allowable power dissipation	Pd max	Mounted on a specified board*	2.0	W
Maximum output current	I _O max	Each output for channel 1 to 5.	0.7	А
Maximum input voltage	V _{IN} B		13	V
MUTE pin voltage	VMUTE		13	V
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

* Mounted on a specified board : 76.1×114.3×1.6mm³, glass epoxy board.

Recommended Operating Conditions at Ta = 25°C

Ī	Parameter	Symbol	Conditions	Ratings	Unit
	Supply voltage	V _{CC}		5.6 to 13	V

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LA6567H

Parameter	Cumhal	Conditions	Ratings			1134	
Parameter	Symbol	Conditions	min	typ	max	Unit	
[Overall Characteristics]							
No-load current drain ON	ICC	All outputs ON, FWD = REV = 0V *1		30	50	mA	
VREF input voltage range	VREF-IN		1		V _{CC} -1	V	
[BTL Amplifier Block]							
Output offset voltage	VOFF	Voltage difference between outputs for BTL AMP, each channel.	-50		50	mV	
Input voltage range	VIN	Input voltage range	0		V _{CC}	V	
Output voltage	VO	Each voltage between V_0+ and V_0- when R_L = 8 Ω . *2	4	5		V	
Closed-circuit voltage gain	VG	Input and output gain.	3.7	4	4.3	deg	
Slew rate	SR	AMP Independent Multiply 2 between outputs. *3		0.5		V/µs	
[H Bridge Block]	·	· ·					
Output voltage	V _O -LOAD	VCONT = 8V *2	5.45	6		V	
Input low level	V _{IN} -L				1	V	
Input high level	V _{IN} -H		2			V	
Output setting voltage VCONT		VCONT = 8V *2	3.0	3.5	4.0	V	
[Regulator Block] (PNP transistor :	: 2SB632K-use)						
Output voltage	Vreg	I _L = 100mA	4.75	5	5.25	V	
Output load fluctuation	ΔVRL	I _L = 0 to 200mA	-50	0	10	mV	
Supply voltage fluctuation	ΔVV _{CC}	V _{CC} = 6 to 12V, I _L = 100mA	-15	21	60	mV	

Electrical Characteristics at Ta = 25° C, V_{CC} = V_{CC} = 8V, VREF = 1.65V, unless especially specified

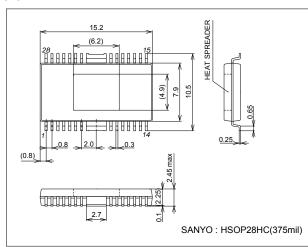
Note $~~^{\star}1$: Current dissipation that is a sum of V_{CC}1 and V_{CC}2 at no load.

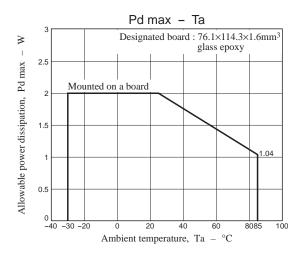
*2 : Voltage difference between both ends of load (8 $\Omega).$ Output saturated.

*3 : Design guarantee value

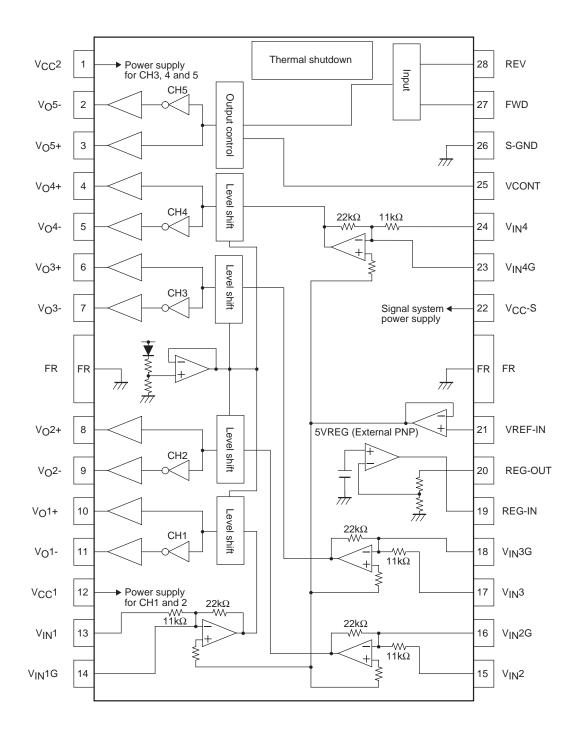
Package Dimensions

unit : mm (typ) 3234B





Block Diagram



Pin Functions

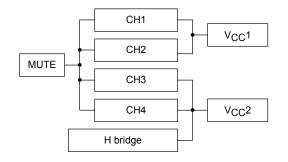
Pin No.	Symbol	Pin descriptions			
1	V _{CC} 2	CH3, 4, and 5 power supplies (Used while being short-circuited to V_{CC}1 and V_{CC}-S)			
2	V _O 5-	Loading output (-)			
3	V _O 5+	Loading output (+)			
4	V _O 4+	Output pin (+) for channel 4			
5	V _O 4-	Output pin (-) for channel 4			
6	V _O 3+	Output pin (+) for channel 3			
7	V _O 3-	Output pin (-) for channel 3			
8	V _O 2+	Output pin (+) for channel 2			
9	V _O 2-	Output pin (-) for channel 2			
10	V _O 1+	Output pin (+) for channel 1			
11	V ₀ 1-	Output pin (-) for channel 1			
12	V _{CC} 1	CH1 and 2(BTL) power supplies (Used while being short-circuited to $V_{\mbox{CC}}\mbox{-S}$ and $V_{\mbox{CC}}\mbox{2})$			
13	V _{IN} 1	Input pin for channel 1			
14	V _{IN} 1G	Input pin for channel 1 (for gain adjustment)			
15	V _{IN} 2	Input pin for channel			
16	V _{IN} 2G	Input pin for channel 2 (for gain adjustment)			
17	V _{IN} 3	Input pin for channel 3			
18	V _{IN} 3G	Input pin for channel 3 (for gain adjustment)			
19	REG-IN	Regulator pin (external PNP base)			
20	REG-OUT	Regulator pin (external PNP collector)			
21	VREF-IN	Reference voltage input pin			
22	V _{CC} -S	Signal system supply (Used while being short-circuited to V_CC1 and V_CC2)			
23	V _{IN} 4G	Input pin for channel 4 (for gain adjustment)			
24	V _{IN} 4	Input pin for channel 4			
25	VCONT	5CH (VLO) output voltage setting pin			
26	S-GND	Signal system GND			
27	FWD	5CH(VLO) Output change pin (FWD), logic input for loading block.			
28	REV	5CH(VLO) Output change pin (REV), logic input for loading block.			

Note : • Center frame (FR) becomes GND for the power system (P-GND). Set this to the minimum potential together with S-GND.

 \bullet Short-circuit power system pins, V_CC-S, V_CC1, and V_CC2 externally for use.

	cription	Γ	ſ	1
Pin No.	Symbol	Pin function	Description	Equivalent circuit
13 14 15 16 17 18 23 24	VIN V _{IN} G	Input	Each input pin	VIN O VING O Vref O Vref O
4 5 7 8 9 10 11	vo	Output	Each output	OUT
2 3 25	V _O 5+ V _O 5- VCONT	V _O 5 Output set for loading block	H bridge output Output setting voltage pin	V ₀ 5+ V ₀ 5- VCONT
27 28	FWD	FWD	H brideg input	O FWD

Relation of MUTE and Power (V_{CC}*)



 * Connect V_CC1 and V_CC2 externally.

H bridge block

FWD	REV	V _O 5+	V _O 5-	Mode
L	L	OFF	OFF	Open *1
L	Н	Н	L	Forward
н	L	L	н	Reversed
н	н	L	L	Break *2

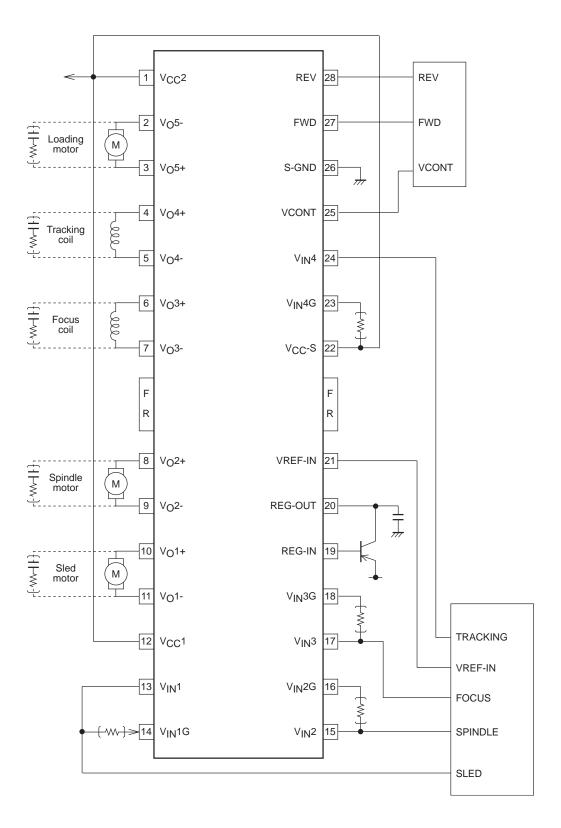
Note *1 : The output has a high Impedance.

 $^{\ast}2$: At brake, the SINK side transistor is ON (short brake).

VLO+ and VLO- are approximately on the GND level.

*3 : VCONT (output setting voltage pin) and VLO can be related as VLO = VCONT-1V (typ).

Sample Application Circuit



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